
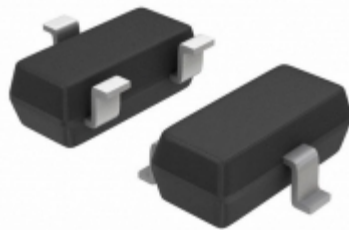

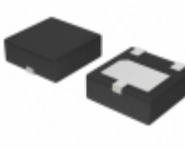
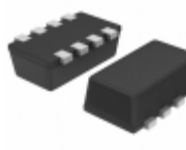


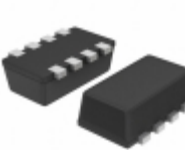
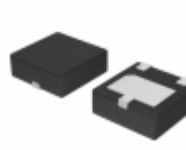

	<h2 style="color: red;">NSS1C200LT1G</h2>
	<p>Hersteller-Teilenummer: NSS1C200LT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: TRANS PNP 100V 2A SOT-23</p> <hr/> <p>Datenblätter:  NSS1C200LT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 167438 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NSS1C200LT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PNP 100V 2A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	167438 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	490mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP
Strom - Kollektor (Ic) (max)	2A
Spannung - Kollektor-Emitter-Durchbruch (max)	100V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 200mA, 2A
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	120 @ 50mA, 2V
Frequenz - Übergang	120MHz
Verpackung	Tape & Reel (TR)


NSS1C200LT1G ist neu im Original. Suche NSS1C200LT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSS1C200LT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSS1C200LT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSS1C200MZ4T3G AMI Semiconductor / ON Semiconductor TRANS PNP 100V 2A SOT-223</p>	 <p>NSS12501UW3T2G AMI Semiconductor / ON Semiconductor TRANS NPN 12V 5A 3-WDFN</p>	 <p>NSS12600CF8T1G AMI Semiconductor / ON Semiconductor TRANS PNP 12V 5A CHIPFET</p>	 <p>NSS1C201LT1G AMI Semiconductor / ON Semiconductor TRANS NPN 100V 2A SOT-23</p>
 <p>NSS1C200MZ4T1G AMI Semiconductor / ON Semiconductor TRANS PNP 100V 2A SOT223</p>	 <p>NSS12601CF8T1G AMI Semiconductor / ON Semiconductor TRANS NPN 12V 6A 1206A CHIPFET</p>	 <p>NSS12500UW3T2G AMI Semiconductor / ON Semiconductor TRANS PNP 12V 5A 3-WDFN</p>	 <p>NSS12201LT1G AMI Semiconductor / ON Semiconductor TRANS NPN 12V 2A SOT-23</p>

heiße Teile

Mehr

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 NSS12100UW3TCG	 NSS12100XV6T1G	 NSS12200LT1G	 NSS12201LT1G	 NSS12500UW3T2G
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 D NSS20101JT1G	 NSS20200LT1G	 NSS20201LT1G	 NSS20201MR6T1G	 NSS20300MR6T1G
 NSS20500UW3T2G	 NSS30070MR6T1G	 NSS30071MR6T1G	 NSS30100LT1G	 NSS30101LT1G
 NSS3010LT1G	 NSS30201MR6T1G	 D NSS35200CF8T1	 NSS35200CF8T1G	 NSS35200MR6T1G
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 NSS40300MZ4T1G	 NSS40301MDR2G	 NSS40301MZ4T1G	 NSS40301MZ4T3G	 NSS40302PDR2G
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 NSS60600MZ4T3G	 NSS60601MZ4T1G	 NSS60601MZ4T3G	 OPA2111AIDR	 TMK212B7225KGHT

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